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Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	16MHz
Connectivity	-
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	3
Program Memory Size	896B (512 x 14)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	64 x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 3x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Through Hole
Package / Case	8-DIP (0.300", 7.62mm)
Supplier Device Package	8-PDIP
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic10lf322-i-p

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PIC10(L)F320/322 Family Types

Device	Data Sheet Index	Program Memory Flash (words)	Data SRAM (bytes)	High Endurance Flash (bytes)	I/O'S ⁽²⁾	8-Bit ADC (ch)	Timers (8-Bit)	PWM	Complementary Wave Generator (CWG)	Configurable Logic Cell (CLC)	Fixed Voltage Reference (FVR)	Numerically Controlled Oscillator (NCO)	Debug ⁽¹⁾	XLP
PIC10(L)F320	(1)	256	64	128	4	3	2	2	1	1	1	1	Н	Y
PIC10(L)F322	(1)	512	64	128	4	3	2	2	1	1	1	1	Н	Y

Note 1: I - Debugging, Integrated on Chip; H - Debugging, Available using Debug Header; E - Emulation, Available using Emulation Header.

2: One pin is input-only.

Data Sheet Index:

1: DS40001585 PIC10(L)F320/322 Data Sheet, 6/8 Pin High Performance, Flash Microcontrollers.

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Address	Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Value on POR, BOR	Value on all other resets
Bank 0		÷								÷	
00h	INDF	Addres	sing this loca	ition uses co	ntents of FS	R to address of	data memory	(not a physical	register)	xxxx xxxx	xxxx xxxx
01h	TMR0				Timer0 M	lodule Registe	er			xxxx xxxx	uuuu uuuu
02h	PCL			Progra	m Counter (F	PC) Least Sigr	nificant Byte		-	0000 0000	0000 0000
03h	STATUS	IRP	RP1	RP0	TO	PD	Z	DC	С	0001 1xxx	000q quuu
04h	FSR			Indi	rect Data Me	mory Address	s Pointer			xxxx xxxx	uuuu uuuu
05h	PORTA	—	—	—	_	RA3	RA2	RA1	RA0	xxxx	uuuu
06h	TRISA	—	—	—	_	(1)	TRISA2	TRISA1	TRISA0	1111	1111
07h	LATA	—	—	—	_	_	LATA2	LATA1	LATA0	xxx	uuu
08h	ANSELA	—	—	—	_	_	ANSA2	ANSA1	ANSA0	111	111
09h	WPUA	—	—	—	-	WPUA3	WPUA2	WPUA1	WPUA0	1111	1111
0Ah	PCLATH	—	—	—	-	_	—	—	PCLH0	0	0
0Bh	INTCON	GIE	PEIE	TMR0IE	INTE	IOCIE	TMR0IF	INTF	IOCIF	0000 0000	0000 000u
0Ch	PIR1	—	ADIF	—	NCO1IF	CLC1IF	_	TMR2IF	—	-0-0 0-0-	-0-0 0-0-
0Dh	PIE1	—	ADIE	—	NCO1IE	CLC1IE		TMR2IE	—	-0-0 0-0-	-0-0 0-0-
0Eh	OPTION_REG	WPUEN	INTEDG	TOCS	T0SE	PSA		PS<2:0>		1111 1111	uuuu uuuu
0Fh	PCON	—	—	—	-	_	—	POR	BOR	qq	uu
10h	OSCCON	—		IRCF<2:0>		HFIOFR	—	LFIOFR	HFIOFS	-110 0-00	-110 0-00
11h	TMR2				Timer2 M	lodule Registe	er			0000 0000	0000 0000
12h	PR2				Timer2 F	Period Registe	r			1111 1111	1111 1111
13h	T2CON	—		TOUT	PS<3:0>	2S<3:0> TMR2ON			S<1:0>	-000 0000	-000 0000
14h	PWM1DCL	PWM1D	CL<1:0>	—	-	_	—	—	—	xx	uu
15h	PWM1DCH				PWM	1DCH<7:0>				xxxx xxxx	uuuu uuuu
16h	PWM1CON	PWM1EN	PWM10E	PWM10UT	PWM1POL	_	_	—	—	0000	0000
17h	PWM2DCL	PWM2D	CL<1:0>	—	-	_	—	—	—	xx	uu
18h	PWM2DCH				PWM	2DCH<7:0>				xxxx xxxx	uuuu uuuu
19h	PWM2CON	PWM2EN	PWM2OE	PWM2OUT	PWM2POL	_	—	—	—	0000	0000
1Ah	IOCAP	—	—	—	-	IOCAP3	IOCAP2	IOCAP1	IOCAP0	0000	0000
1Bh	IOCAN	—	—	—	-	IOCAN3	IOCAN2	IOCAN1	IOCAN0	0000	0000
1Ch	IOCAF	—	—	—	-	IOCAF3	IOCAF2	IOCAF1	IOCAF0	0000	0000
1Dh	FVRCON	FVREN	FVRRDY	TSEN	TSRNG	_	_	ADFVF	R<1:0>	0x0000	0x0000
1Eh	ADRES				A/D Re	sult Register				xxxx xxxx	uuuu uuuu
1Fh	ADCON		ADCS<2:0>			CHS<2:0>		GO/ DONE	ADON	0000 0000	0000 0000

TABLE	2-3: SF	ECIAL F	N REGI	STER SL	JMMARY	(BANK (I)
							_

Legend: x = unknown, u = unchanged, q = value depends on condition, - = unimplemented, read as '0', r = reserved. Shaded locations are unimplemented, read as '0'.

Note 1: Unimplemented, read as '1'.

4.0 OSCILLATOR MODULE

4.1 Overview

The oscillator module has a variety of clock sources and selection features that allow it to be used in a range of applications while maximizing performance and minimizing power consumption. Figure 4-1 illustrates a block diagram of the oscillator module.

The system can be configured to use an internal calibrated high-frequency oscillator as clock source, with a choice of selectable speeds via software.

Clock source modes are configured by the FOSC bit in Configuration Word (CONFIG).

- 1. EC oscillator from CLKIN.
- 2. INTOSC oscillator, CLKIN not enabled.





5.4 Low-Power Brown-out Reset (LPBOR)

The Low-Power Brown-Out Reset (LPBOR) is an essential part of the Reset subsystem. Refer to Figure 5-1 to see how the BOR interacts with other modules.

The LPBOR is used to monitor the external VDD pin. When too low of a voltage is detected, the device is held in Reset. When this occurs, a register bit ($\overline{\text{BOR}}$) is changed to indicate that a BOR Reset has occurred. The same bit is set for both the BOR and the LPBOR. Refer to Register 5-2.

5.4.1 ENABLING LPBOR

The LPBOR is controlled by the LPBOR bit of Configuration Word. When the device is erased, the LPBOR module defaults to enabled.

5.4.1.1 LPBOR Module Output

The output of the LPBOR module is a signal indicating whether or not a Reset is to be asserted. This signal is OR'd together with the Reset signal of the BOR module to provide the generic BOR signal which goes to the PCON register and to the power control block.

5.5 MCLR

The $\overline{\text{MCLR}}$ is an optional external input that can reset the device. The $\overline{\text{MCLR}}$ function is controlled by the MCLRE and the LVP bit of Configuration Word (Table 5-2).

TABLE 5-2: MCLR CONFIGURATION

MCLRE	LVP	MCLR
0	0	Disabled
1	0	Enabled
x	1	Enabled

5.5.1 MCLR ENABLED

When MCLR is enabled and the pin is held low, the device is held in Reset. The MCLR pin is connected to VDD through an internal weak pull-up.

The device has a noise filter in the $\overline{\text{MCLR}}$ Reset path. The filter will detect and ignore small pulses.

```
Note: A Reset does not drive the \overline{MCLR} pin low.
```

5.5.2 MCLR DISABLED

When MCLR is disabled, the pin functions as a general purpose input and the internal weak pull-up is under software control.

5.6 Watchdog Timer (WDT) Reset

The Watchdog Timer generates a Reset if the firmware does not issue a CLRWDT instruction within the time-out period. The TO and PD bits in the STATUS register are changed to indicate the WDT Reset. See **Section 8.0** "**Watchdog Timer**" for more information.

5.7 Programming Mode ICSP Exit

Upon exit of Programming mode, the device will behave as if a POR had just occurred.

5.8 Power-Up Timer

The Power-up Timer optionally delays device execution after a BOR or POR event. This timer is typically used to allow VDD to stabilize before allowing the device to start running.

The Power-up Timer is controlled by the $\overrightarrow{\text{PWRTE}}$ bit of Configuration Word.

5.9 Start-up Sequence

Upon the release of a POR or BOR, the following must occur before the device will begin executing:

- 1. Power-up Timer runs to completion (if enabled).
- 2. MCLR must be released (if enabled).

The total time-out will vary based on oscillator configuration and Power-up Timer configuration. See **Section 4.0 "Oscillator Module"** for more information.

The Power-up Timer runs independently of MCLR Reset. If MCLR is kept low long enough, the Power-up Timer will expire. Upon bringing MCLR high, the device will begin execution after 10 FOSC cycles (see Figure 5-3). This is useful for testing purposes or to synchronize more than one device operating in parallel.

6.1 Operation

Interrupts are disabled upon any device Reset. They are enabled by setting the following bits:

- · GIE bit of the INTCON register
- Interrupt Enable bit(s) for the specific interrupt event(s)
- PEIE bit of the INTCON register (if the Interrupt Enable bit of the interrupt event is contained in the PIE1 register)

The INTCON and PIR1 registers record individual interrupts via interrupt flag bits. Interrupt flag bits will be set, regardless of the status of the GIE, PEIE and individual interrupt enable bits.

The following events happen when an interrupt event occurs while the GIE bit is set:

- · Current prefetched instruction is flushed
- · GIE bit is cleared
- Current Program Counter (PC) is pushed onto the stack
- PC is loaded with the interrupt vector 0004h

The firmware within the Interrupt Service Routine (ISR) should determine the source of the interrupt by polling the interrupt flag bits. The interrupt flag bits must be cleared before exiting the ISR to avoid repeated interrupts. Because the GIE bit is cleared, any interrupt that occurs while executing the ISR will be recorded through its interrupt flag, but will not cause the processor to redirect to the interrupt vector.

The ${\tt RETFIE}$ instruction exits the ISR by popping the previous address from the stack, and setting the GIE bit.

For additional information on a specific interrupt's operation, refer to its peripheral chapter.

- Note 1: Individual interrupt flag bits are set, regardless of the state of any other enable bits.
 - 2: All interrupts will be ignored while the GIE bit is cleared. Any interrupt occurring while the GIE bit is clear will be serviced when the GIE bit is set again.

6.2 Interrupt Latency

Interrupt latency is defined as the time from when the interrupt event occurs to the time code execution at the interrupt vector begins. The latency for synchronous interrupts is three or four instruction cycles. For asynchronous interrupts, the latency is three to five instruction cycles, depending on when the interrupt occurs. See Figure 6-2 and **Section 6.3 "Interrupts During Sleep"** for more details.

9.2.3 ERASING FLASH PROGRAM MEMORY

While executing code, program memory can only be erased by rows. To erase a row:

- 1. Load the PMADRH:PMADRL register pair with any address within the row to be erased.
- 2. Clear the CFGS bit of the PMCON1 register.
- 3. Set the FREE and WREN bits of the PMCON1 register.
- 4. Write 55h, then AAh, to PMCON2 (Flash programming unlock sequence).
- 5. Set control bit WR of the PMCON1 register to begin the erase operation.

See Example 9-2.

After the "BSF PMCON1, WR" instruction, the processor requires two cycles to set up the erase operation. The user must place two NOP instructions after the WR bit is set. The processor will halt internal operations for the typical 2 ms erase time. This is not Sleep mode as the clocks and peripherals will continue to run. After the erase cycle, the processor will resume operation with the third instruction after the PMCON1 write instruction.

FIGURE 9-4:

FLASH PROGRAM MEMORY ERASE FLOWCHART



EXAMPLE 9-2: ERASING ONE ROW OF PROGRAM MEMORY

; This row erase routine assumes the following:

; 1. A valid address within the erase row is loaded in ADDRH:ADDRL

; 2. ADDRH and ADDRL are located in shared data memory $0\,\mathrm{x}70$ - $0\,\mathrm{x}7F$ (common RAM)

	BCF	INTCON,GIE	; Disable ints so required sequences will execute properly
	BANKSEL	PMADRL	; not required on devices with 1 Bank of SFRs
	MOVF	ADDRL,W	; Load lower 8 bits of erase address boundary
	MOVWF	PMADRL	
	MOVF	ADDRH,W	; Load upper 6 bits of erase address boundary
	MOVWF	PMADRH	
	BCF	PMCON1,CFGS	; Not configuration space
	BSF	PMCON1, FREE	; Specify an erase operation
	BSF	PMCON1,WREN	; Enable writes
	MOVLW	55h	; Start of required sequence to initiate erase
_ a)	MOVWF	PMCON2	; Write 55h
nce	MOVLW	0AAh	i
ine Ine	MOVWF	PMCON2	; Write AAh
Sec. 2	BSF	PMCON1,WR	; Set WR bit to begin erase
- 05	NOP		; NOP instructions are forced as processor starts
	NOP		; row erase of program memory.
L			;
			; The processor stalls until the erase process is complete
			; after erase processor continues with 3rd instruction
	BCF	PMCON1,WREN	; Disable writes
	BSF	INTCON,GIE	; Enable interrupts



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W-0/0	W-0/0	W-0/0	W-0/0	W-0/0	W-0/0	W-0/0	W-0/0
		Prog	gram Memory	/ Control Regis	ter 2		
bit 7							bit 0
Legend:							
R = Readable b	bit	W = Writable I	bit	U = Unimpler	nented bit, read	l as '0'	
S = Bit can only	/ be set	x = Bit is unkn	iown	-n/n = Value	at POR and BO	R/Value at all c	other Resets
'1' = Bit is set		'0' = Bit is clea	ared				

REGISTER 9-6: PMCON2: PROGRAM MEMORY CONTROL 2 REGISTER

bit 7-0 Flash Memory Unlock Pattern bits

To unlock writes, a 55h must be written first, followed by an AAh, before setting the WR bit of the PMCON1 register. The value written to this register is used to unlock the writes. There are specific timing requirements on these writes.

TABLE 9-3: SUMMARY OF REGISTERS ASSOCIATED WITH FLASH PROGRAM MEMORY

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
INTCON	GIE	PEIE	TMR0IE	INTE	IOCIE	TMR0IF	INTF	IOCIF	40
PMCON1	_	CFGS	LWLO	FREE	WRERR	WREN	WR	RD	65
PMCON2	Program Memory Control Register 2								66
PMADRL				PMAD	R<7:0>				64
PMADRH	_	_	_	_	-	_	_	PMADR8	64
PMDATL	PMDAT<7:0>								63
PMDATH	_	— — РМDAT<13:8>							63

Legend: — = unimplemented location, read as '0'. Shaded cells are not used by Flash program memory module.

TABLE 9-4: SUMMARY OF CONFIGURATION WORD WITH FLASH PROGRAM MEMORY

Name	Bits	Bit -/7	Bit -/6	Bit 13/5	Bit 12/4	Bit 11/3	Bit 10/2	Bit 9/1	Bit 8/0	Register on Page
	13:8	—	—	—	WRT<1:0>		BORV	LPBOR	LVP	20
CONFIG	7:0	CP	MCLR	PWRTE	WDTE<1:0>		BOREN<1:0>		FOSC	20

Legend: — = unimplemented location, read as '0'. Shaded cells are not used by Flash program memory.

TABLE 10-2: SUMMARY OF REGISTERS ASSOCIATED WITH PORTA

Name	Bit 7	Bit 6	Bit 5	Bit 4	Bit 3	Bit 2	Bit 1	Bit 0	Register on Page
ANSELA	—	—	—	—	—	ANSA2	ANSA1	ANSA0	70
IOCAF	—	—	—	—	IOCAF3	IOCAF2	IOCAF1	IOCAF0	76
IOCAN	—	—	—	—	IOCAN3	IOCAN2	IOCAN1	IOCAN0	75
IOCAP	—	—	—	—	IOCAP3	IOCAP2	IOCAP1	IOCAP0	75
LATA	—	—	—	—	—	LATA2	LATA1	LATA0	70
PORTA	—	—	—	—	RA3	RA2	RA1	RA0	69
TRISA	_	_	_	_	(1)	TRISA2	TRISA1	TRISA0	69
WPUA	—	—	—	—	WPUA3	WPUA2	WPUA1	WPUA0	71

Legend: x = unknown, u = unchanged, – = unimplemented locations read as '0'. Shaded cells are not used by PORTA.

Note 1: Unimplemented, read as '1'.

14.0 TEMPERATURE INDICATOR MODULE

This family of devices is equipped with a temperature circuit designed to measure the operating temperature of the silicon die. The circuit's range of operating temperature falls between of -40° C and $+85^{\circ}$ C. The output is a voltage that is proportional to the device temperature. The output of the temperature indicator is internally connected to the device ADC.

The circuit may be used as a temperature threshold detector or a more accurate temperature indicator, depending on the level of calibration performed. A one-point calibration allows the circuit to indicate a temperature closely surrounding that point. A two-point calibration allows the circuit to sense the entire range of temperature more accurately. Reference Application Note AN1333, *"Use and Calibration of the Internal Temperature Indicator"* (DS01333) for more details regarding the calibration process.

14.1 Circuit Operation

Figure 14-1 shows a simplified block diagram of the temperature circuit. The proportional voltage output is achieved by measuring the forward voltage drop across multiple silicon junctions.

Equation 14-1 describes the output characteristics of the temperature indicator.

EQUATION 14-1: VOUT RANGES

High Range: VOUT = VDD - 4VT

Low Range: VOUT = VDD - 2VT

The temperature sense circuit is integrated with the Fixed Voltage Reference (FVR) module. See **Section 12.0 "Fixed Voltage Reference (FVR)"** for more information.

The circuit is enabled by setting the TSEN bit of the FVRCON register. When disabled, the circuit draws no current.

The circuit operates in either high or low range. The high range, selected by setting the TSRNG bit of the FVRCON register, provides a wider output voltage. This provides more resolution over the temperature range, but may be less consistent from part to part. This range requires a higher bias voltage to operate and thus, a higher VDD is needed.

The low range is selected by clearing the TSRNG bit of the FVRCON0 register. The low range generates a lower voltage drop and thus, a lower bias voltage is needed to operate the circuit. The low range is provided for low voltage operation.

FIGURE 14-1: TEMPERATURE CIRCUIT DIAGRAM



14.2 Minimum Operating VDD vs. Minimum Sensing Temperature

When the temperature circuit is operated in low range, the device may be operated at any operating voltage that is within specifications.

When the temperature circuit is operated in high range, the device operating voltage, VDD, must be high enough to ensure that the temperature circuit is correctly biased.

Table 14-1 shows the recommended minimum $\mathsf{V}\mathsf{D}\mathsf{D}$ vs. range setting.

TABLE 14-1: RECOMMENDED VDD VS. RANGE

Min. VDD, TSRNG = 1	Min. VDD, TSRNG = 0
3.6V	1.8V

14.3 Temperature Output

The output of the circuit is measured using the internal Analog-to-Digital Converter. A channel is reserved for the temperature circuit output. Refer to **Section 15.0 "Analog-to-Digital Converter (ADC) Module"** for detailed information.

14.4 ADC Acquisition Time

To ensure accurate temperature measurements, the user must wait at least 200 μ s after the ADC input multiplexer is connected to the temperature indicator output before the conversion is performed. In addition, the user must wait 200 μ s between sequential conversions of the temperature indicator output.

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15.1.5 INTERRUPTS

The ADC module allows for the ability to generate an interrupt upon completion of an Analog-to-Digital conversion. The ADC Interrupt Flag is the ADIF bit in the PIR1 register. The ADC Interrupt Enable is the ADIE bit in the PIE1 register. The ADIF bit must be cleared in software.

Note:	The ADIF bit is set at the completion of
	every conversion, regardless of whether
	or not the ADC interrupt is enabled.

This interrupt can be generated while the device is operating or while in Sleep. If the device is in Sleep, the interrupt will wake-up the device. Upon waking from Sleep, the next instruction following the SLEEP instruction is always executed. If the user is attempting to wake-up from Sleep and resume in-line code execution, the GIE and PEIE bits of the INTCON register must be disabled. If the GIE and PEIE bits of the INTCON register are enabled, execution will switch to the Interrupt Service Routine.

15.2 ADC Operation

15.2.1 STARTING A CONVERSION

To enable the ADC module, the ADON bit of the ADCON register must be set to a '1'. Setting the GO/ DONE bit of the ADCON register to a '1' will start the Analog-to-Digital conversion.

Note:	The GO/DONE bit should not be set in the				
	same instruction that turns on the ADC.				
	Refer to Section 15.2.5 "A/D Conver-				
	sion Procedure".				

15.2.2 COMPLETION OF A CONVERSION

When the conversion is complete, the ADC module will:

- Clear the GO/DONE bit
- · Set the ADIF Interrupt Flag bit
- Update the ADRES register with new conversion result

15.2.3 TERMINATING A CONVERSION

If a conversion must be terminated before completion, the GO/DONE bit can be cleared in software. The ADRES register will be updated with the partially complete Analog-to-Digital conversion sample. Incomplete bits will match the last bit converted.

Note:	A device Reset forces all registers to their				
	Reset state. Thus, the ADC module is				
	turned off and any pending conversion is				
	terminated.				

15.2.4 ADC OPERATION DURING SLEEP

The ADC module can operate during Sleep. This requires the ADC clock source to be set to the FRC option. When the FRC clock source is selected, the ADC waits one additional instruction before starting the conversion. This allows the SLEEP instruction to be executed, which can reduce system noise during the conversion. If the ADC interrupt is enabled, the device will wake-up from Sleep when the conversion completes. If the ADC interrupt is disabled, the ADC module is turned off after the conversion completes, although the ADON bit remains set.

When the ADC clock source is something other than FRC, a SLEEP instruction causes the present conversion to be aborted and the ADC module is turned off, although the ADON bit remains set.

18.0 PULSE-WIDTH MODULATION (PWM) MODULE

The PWM module generates a Pulse-Width Modulated signal determined by the duty cycle, period, and resolution that are configured by the following registers:

- PR2
- T2CON
- PWMxDCH
- PWMxDCL
- PWMxCON

Figure 18-1 shows a simplified block diagram of PWM operation.

Figure 18-2 shows a typical waveform of the PWM signal.



For a step-by-step procedure on how to set up this module for PWM operation, refer to **Section 18.1.9** "Setup for PWM Operation using PWMx Pins".

FIGURE 18-2: PWM OUTPUT



18.1 PWMx Pin Configuration

All PWM outputs are multiplexed with the PORT data latch. The user must configure the pins as outputs by clearing the associated TRIS bits.

Note: Clearing the PWMxOE bit will relinquish control of the PWMx pin.

18.1.1 FUNDAMENTAL OPERATION

The PWM module produces a 10-bit resolution output. Timer2 and PR2 set the period of the PWM. The PWMxDCL and PWMxDCH registers configure the duty cycle. The period is common to all PWM modules, whereas the duty cycle is independently controlled.

Note: The Timer2 postscaler is not used in the determination of the PWM frequency. The postscaler could be used to have a servo update rate at a different frequency than the PWM output.

All PWM outputs associated with Timer2 are set when TMR2 is cleared. Each PWMx is cleared when TMR2 is equal to the value specified in the corresponding PWMxDCH (8 MSb) and PWMxDCL<7:6> (2 LSb) registers. When the value is greater than or equal to PR2, the PWM output is never cleared (100% duty cycle).

Note: The PWMxDCH and PWMxDCL registers are double buffered. The buffers are updated when Timer2 matches PR2. Care should be taken to update both registers before the timer match occurs.

18.1.2 PWM OUTPUT POLARITY

The output polarity is inverted by setting the PWMxPOL bit of the PWMxCON register.

18.1.3 PWM PERIOD

The PWM period is specified by the PR2 register of Timer2. The PWM period can be calculated using the formula of Equation 18-1.

EQUATION 18-1: PWM PERIOD

 $PWM Period = [(PR2) + 1] \bullet 4 \bullet Tosc \bullet$ (TMR2 Prescale Value)

Note: Tosc = 1/Fosc

When TMR2 is equal to PR2, the following three events occur on the next increment cycle:

- · TMR2 is cleared
- The PWM output is active. (Exception: When the PWM duty cycle = 0%, the PWM output will remain inactive.)
- The PWMxDCH and PWMxDCL register values are latched into the buffers.

Note:	The Timer2 postscaler has no effect on the
	PWM operation.

18.1.4 PWM DUTY CYCLE

The PWM duty cycle is specified by writing a 10-bit value to the PWMxDCH and PWMxDCL register pair. The PWMxDCH register contains the eight MSbs and the PWMxDCL<7:6>, the two LSbs. The PWMxDCH and PWMxDCL registers can be written to at any time.

Equation 18-2 is used to calculate the PWM pulse width.

Equation 18-3 is used to calculate the PWM duty cycle ratio.

EQUATION 18-2: PULSE WIDTH

Pulse Width = (PWMxDCH:PWMxDCL<7:6>) •

TOSC • (TMR2 Prescale Value)

Note: Tosc = 1/Fosc

EQUATION 18-3: DUTY CYCLE RATIO

 $Duty Cycle Ratio = \frac{(PWMxDCH:PWMxDCL<7:6>)}{4(PR2+1)}$

The 8-bit timer TMR2 register is concatenated with the two Least Significant bits of 1/Fosc, adjusted by the Timer2 prescaler to create the 10-bit time base. The system clock is used if the Timer2 prescaler is set to 1:1.

21.9 Auto-shutdown Control

Auto-shutdown is a method to immediately override the CWG output levels with specific overrides that allow for safe shutdown of the circuit. The shutdown state can be either cleared automatically or held until cleared by software.

21.9.1 SHUTDOWN

The Shutdown state can be entered by either of the following two methods:

- Software generated
- External Input

21.9.1.1 Software Generated Shutdown

Setting the GxASE bit of the CWGxCON2 register will force the CWG into the shutdown state.

When auto-restart is disabled, the shutdown state will persist as long as the GxASE bit is set.

When auto-restart is enabled, the GxASE bit will clear automatically and resume operation on the next rising edge event. See Figure 21-6.

21.9.1.2 External Input Source

External shutdown inputs provide the fastest way to safely suspend CWG operation in the event of a Fault condition. When any of the selected shutdown inputs goes high, the CWG outputs will immediately go to the selected override levels without software delay. Any combination of two input sources can be selected to cause a shutdown condition. The two sources are:

- LC10UT
- CWG1FLT

Shutdown inputs are selected using the GxASDS0 and GxASDS1 bits of the CWGxCON2 register. (Register 21-3).

Note:	Shutdown inputs are level sensitive, not
	edge sensitive. The shutdown state can-
	not be cleared, except by disabling auto-
	shutdown, as long as the shutdown input
	level persists.

21.10 Operation During Sleep

The CWG module operates independently from the system clock and will continue to run during Sleep, provided that the clock and input sources selected remain active.

The HFINTOSC remains active during Sleep, provided that the CWG module is enabled, the input source is active, and the HFINTOSC is selected as the clock source, regardless of the system clock source selected.

In other words, if the HFINTOSC is simultaneously selected as the system clock and the CWG clock source, when the CWG is enabled and the input source is active, the CPU will go idle during Sleep, but the CWG will continue to operate and the HFINTOSC will remain active.

This will have a direct effect on the Sleep mode current.

TABLE 24-4: I/O PORTS

Standard Operating Conditions (unless otherwise stated)									
Param No.	Sym.	Characteristic	Min.	Тур†	Max.	Units	Conditions		
	VIL	Input Low Voltage							
		I/O PORT:							
D032		with TTL buffer	—		0.8	V	$4.5V \leq V\text{DD} \leq 5.5V$		
D032A			—		0.15 VDD	V	$1.8V \leq V\text{DD} \leq 4.5V$		
D033		with Schmitt Trigger buffer	—		0.2 VDD	V	$2.0V \leq V\text{DD} \leq 5.5V$		
D034		MCLR	—		0.2 VDD	V			
	VIH	Input High Voltage							
		I/O ports:							
D040		with TTL buffer	2.0			V	$4.5V \leq V\text{DD} \leq 5.5V$		
D040A			0.25 VDD + 0.8	_	—	V	$1.8V \le V\text{DD} \le 4.5V$		
D041		with Schmitt Trigger buffer	0.8 VDD	_	—	V	$2.0V \leq V\text{DD} \leq 5.5V$		
D042		MCLR	0.8 VDD		—	V			
	lı∟	Input Leakage Current ⁽²⁾							
D060		I/O ports	—	± 5	± 125	nA	$Vss \le VPIN \le VDD$, Pin at		
				± 5	± 1000	nA	high-impedance @ 85°C 125°C		
D061		MCLR	_	± 50	± 200	nA	$Vss \le VPIN \le VDD @ 85^{\circ}C$		
	IPUR	Weak Pull-up Current				•			
D070*			25 25	100 140	200 300	μA	VDD = 3.3V, VPIN = VSS VDD = 5.0V, VPIN = VSS		
	Vol	Output Low Voltage							
D080		I/O ports	_	_	0.6	V	IOL = 8mA, VDD = 5V IOL = 6mA, VDD = 3.3V IOL = 1.8mA, VDD = 1.8V		
	Voн	Output High Voltage	Output High Voltage						
D090		I/O ports	Vdd - 0.7	_	_	V	IOH = 3.5mA, VDD = 5V IOH = 3mA, VDD = 3.3V IOH = 1mA, VDD = 1.8V		

These parameters are characterized but not tested.

Data in "Typ" column is at 3.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are t not tested.

Note 1: Negative current is defined as current sourced by the pin.

2: The leakage current on the MCLR pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltages.

Param No.	Sym.	Characteristic	Min.	Тур†	Max.	Units	Conditions
		Program Memory Programming Specifications					
D110	VIHH	Voltage on MCLR/VPP pin	8.0	_	9.0	V	(Note 2)
D111	IDDP	Supply Current during Programming	—	_	10	mA	
D112		VDD for Bulk Erase	2.7	—	VDD max.	V	
D113	VPEW	VDD for Write or Row Erase	Vdd min.	—	VDD max.	V	
D114	IPPPGM	Current on MCLR/VPP during Erase/Write	-	_	1.0	mA	
D115	IDDPGM	Current on VDD during Erase/Write			5.0	mA	
		Program Flash Memory					
D121	EР	Cell Endurance	10K	_	_	E/W	-40°C to +85°C (Note 1)
D122	Vpr	VDD for Read	VDD min.	—	VDD max.	V	
D123	TIW	Self-timed Write Cycle Time	_	2	2.5	ms	
D124	TRETD	Characteristic Retention	40	—	—	Year	Provided no other specifications are violated
D125	EHEFC	High-Endurance Flash Cell	100K	—	—	E/W	$0^{\circ}C \le TA \le 60$, lower byte last 128 addresses

Standard Operating Conditions (unless otherwise stated)

† Data in "Typ" column is at 3.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

Note 1: Self-write and Block Erase.

2: Required only if single-supply programming is disabled.



FIGURE 24-12: A/D CONVERSION TIMING (NORMAL MODE)

FIGURE 24-13: A/D CONVERSION TIMING (SLEEP MODE)



TABLE 27-1:8-LEAD 2x3 DFN (MC) TOP
MARKING

Part Number	Marking
PIC10F322(T)-I/MC	BAA
PIC10F322(T)-E/MC	BAB
PIC10F320(T)-I/MC	BAC
PIC10F320(T)-E/MC	BAD
PIC10LF322(T)-I/MC	BAF
PIC10LF322(T)-E/MC	BAG
PIC10LF320(T)-I/MC	BAH
PIC10LF320(T)-E/MC	BAJ

TABLE 27-2:6-LEAD SOT-23 (OT)PACKAGE TOP MARKING

Part Number	Marking
PIC10F322(T)-I/OT	LA/LJ
PIC10F322(T)-E/OT	LB/LK
PIC10F320(T)-I/OT	LC
PIC10F320(T)-E/OT	LD
PIC10LF322(T)-I/OT	LE
PIC10LF322(T)-E/OT	LF
PIC10LF320(T)-I/OT	LG
PIC10LF320(T)-E/OT	LH